

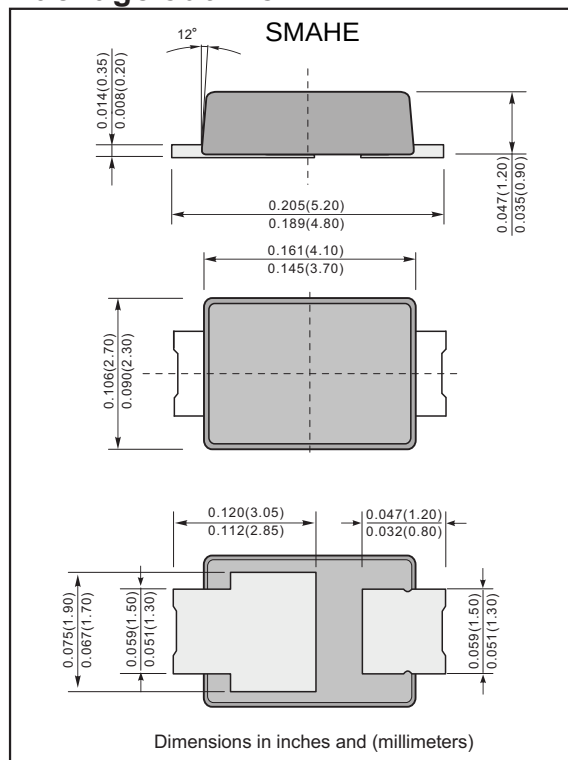
### Features

- Batch process design, excellent power dissipation offers better reverse leakage current and thermal resistance
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- Guardring for overvoltage protection
- Ultra high-speed switching
- Silicon epitaxial planar chip, metal silicon junction
- Lead-free parts meet RoHS requirements
- Compliant to Halogen-free

### Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic,SMAHE
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any

### Package outline



### Maximum ratings and Electrical characteristics (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

| PARAMETER                         | CONDITIONS                                      | Symbol          | MIN. | TYP. | MAX. | UNIT                 |
|-----------------------------------|-------------------------------------------------|-----------------|------|------|------|----------------------|
| Forward rectified current         | See Fig.1                                       | $I_O$           |      |      | 5.0  | A                    |
| Forward surge current             | 8.3ms single half sine-wave (JEDEC methode)     | $I_{FSM}$       |      |      | 120  | A                    |
| Reverse current                   | $V_R = V_{RRM} \quad T_a = 25^{\circ}\text{C}$  | $I_R$           |      |      | 1.0  | mA                   |
|                                   | $V_R = V_{RRM} \quad T_a = 100^{\circ}\text{C}$ |                 |      |      | 50   |                      |
| Thermal resistance <sup>(1)</sup> | Junction to ambient                             | $R_{\theta JA}$ |      | 95   |      | $^{\circ}\text{C/W}$ |
|                                   | Junction to case                                | $R_{\theta JC}$ |      | 20   |      | $^{\circ}\text{C/W}$ |
| Diode junction capacitance        | f=1MHz and applied 4V DC reverse voltage        | $C_J$           |      | 280  |      | pF                   |
| Storage temperature               |                                                 | $T_{STG}$       | -55  |      | +150 | $^{\circ}\text{C}$   |

(1) P.C.B. mounted with 0.2" X 0.2" (5 X 5 mm) copper pad areas.

| SYMBOLS     | $V_{RRM}^{*1}$<br>(V) | $V_{RMS}^{*2}$<br>(V) | $V_R^{*3}$<br>(V) | $V_F^{*4}$<br>(V) | Operating temperature<br>$T_J, (^{\circ}\text{C})$ |
|-------------|-----------------------|-----------------------|-------------------|-------------------|----------------------------------------------------|
| SS54-AHE-C  | 40                    | 28                    | 40                | 0.55              | -55 to +150                                        |
| SS56-AHE-C  | 60                    | 42                    | 60                | 0.70              |                                                    |
| SS510-AHE-C | 100                   | 70                    | 100               | 0.85              |                                                    |
| SS515-AHE-C | 150                   | 105                   | 150               | 0.95              |                                                    |
| SS520-AHE-C | 200                   | 140                   | 200               |                   |                                                    |

\*1 Repetitive peak reverse voltage

\*2 RMS voltage

\*3 Continuous reverse voltage

\*4 Maximum forward voltage@ $I_F=5.0\text{A}$

### Rating and characteristic curves

Fig.1 Forward Current Derating Curve

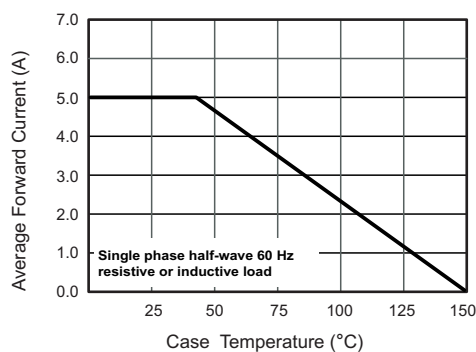


Fig.2 Typical Reverse Characteristics

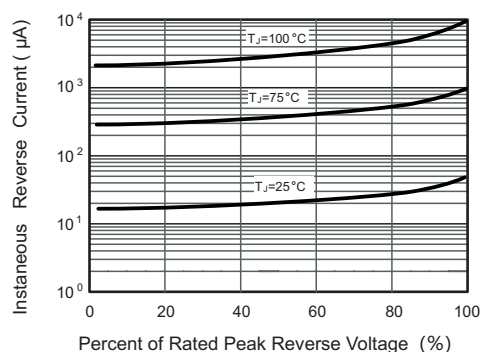


Fig.3 Typical Forward Characteristic

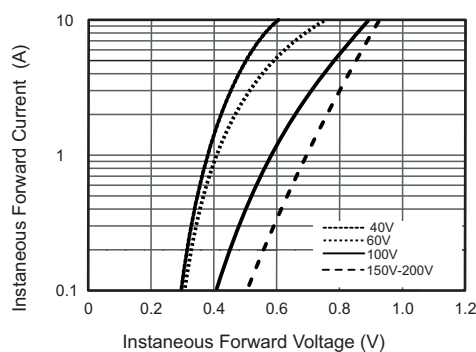


Fig.4 Typical Junction Capacitance

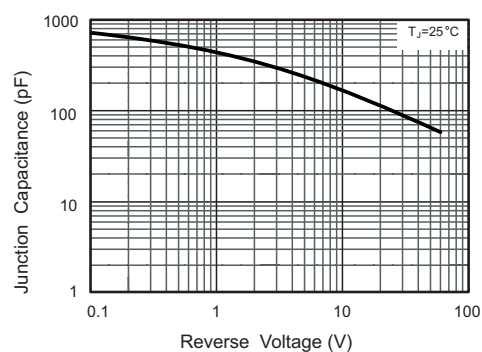
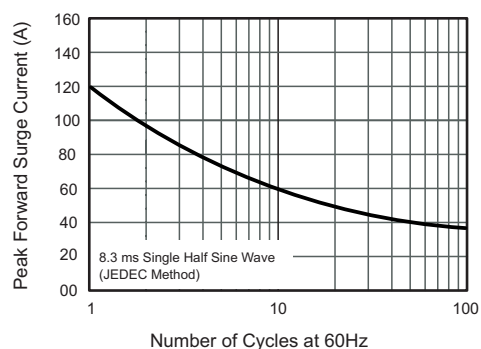


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



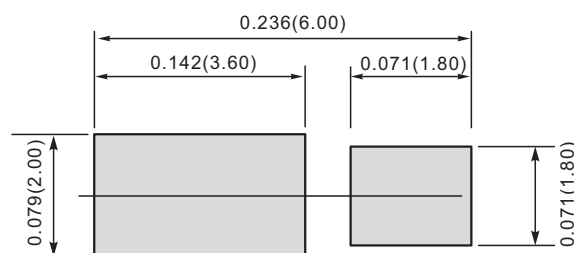
### Pinning information

| Pin                        | Simplified outline                                                                | Symbol                                                                              |
|----------------------------|-----------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|
| Pin1 cathode<br>Pin2 anode |  |  |

### Marking

| Type number | Marking code |
|-------------|--------------|
| SS54-AHE-C  | SS54         |
| SS56-AHE-C  | SS56         |
| SS510-AHE-C | SS510        |
| SS515-AHE-C | SS515        |
| SS520-AHE-C | SS520        |

### Suggested solder pad layout



Dimensions in inches and (millimeters)